

H7N1004FN

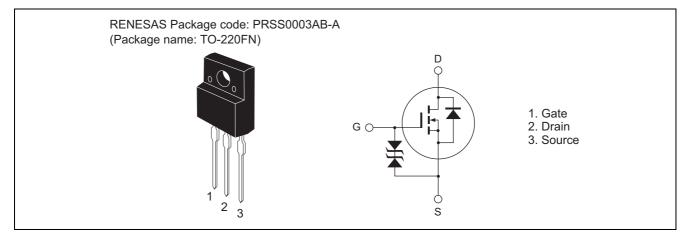
Silicon N-Channel MOSFET High-Speed Power Switching

> REJ03G1593-0100 Rev.1.00 Oct 23, 2007

Features

- Low on-resistance
- $R_{DS(on)} = 25 \text{ m}\Omega \text{ typ.}$
- Low drive current
- Available for 4.5 V gate drive

Outline



Absolute Maximum Ratings

			$(Ta = 25^{\circ}C)$
ltem	Symbol	Value	Unit
Drain to source voltage	V _{DSS}	100	V
Gate to source voltage	V _{GSS}	±20	V
Drain current	I _D	25	А
Drain peak current	I _D (pulse) Note1	100	А
Body-drain diode reverse drain current	I _{DR}	25	А
Avalanche current	I _{AP} Note 3	15	А
Avalanche energy	E _{AR} Note 3	22.5	mJ
Channel dissipation	Pch Note 2	25	W
Channel temperature	Tch	150	٥°
Storage temperature	Tstg	-55 to +150	٥°

Notes: 1. $PW \le 10 \ \mu s$, duty cycle $\le 1\%$

2. Value at Tc = 25°C

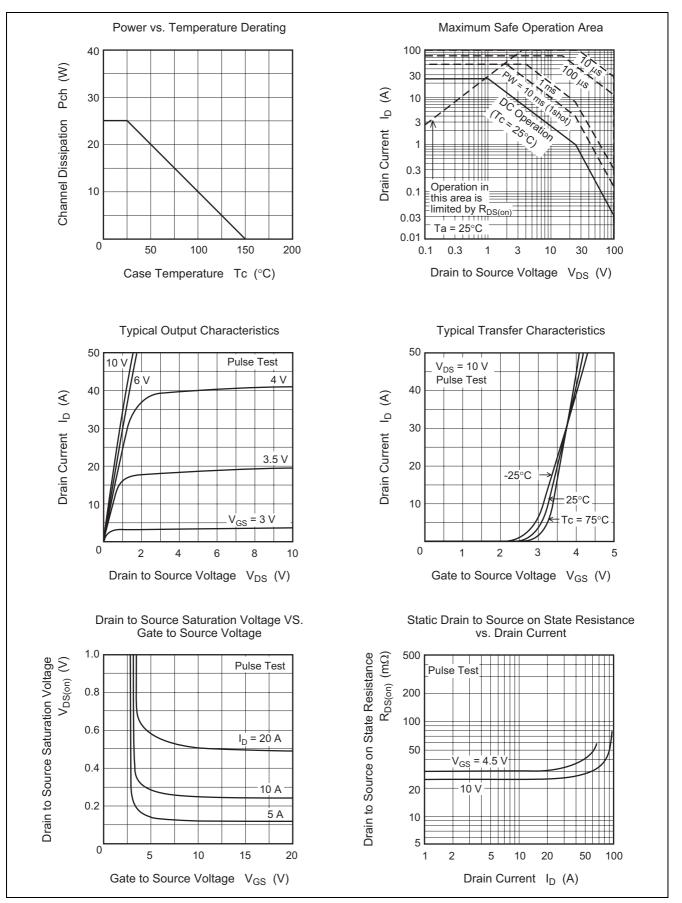
3. Value at Tch = 25°C, Rg \geq 50 Ω

Electrical Characteristics

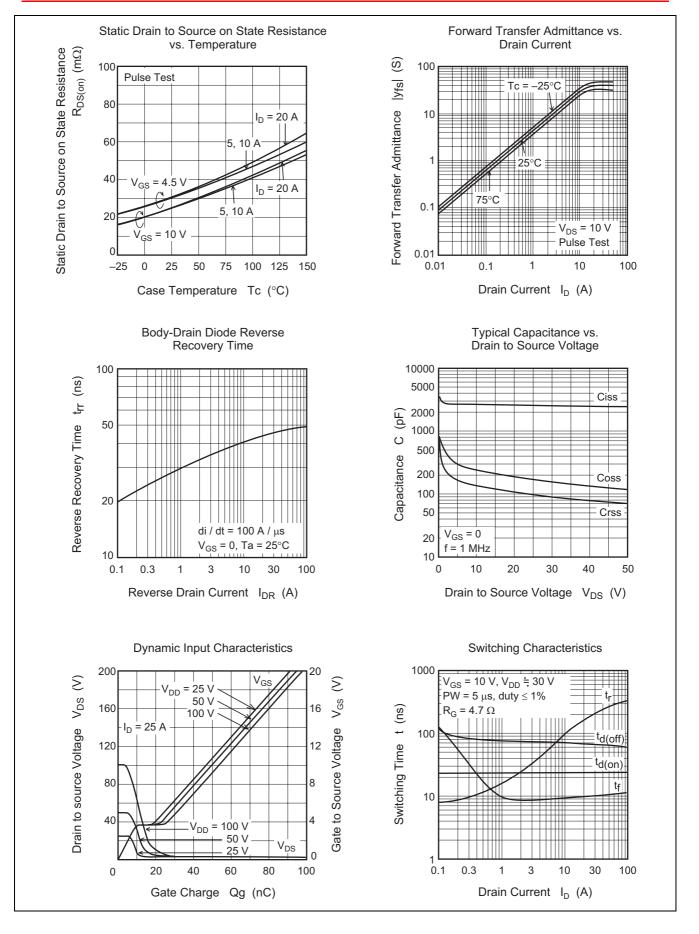
						$(Ta = 25^{\circ}C)$
Item	Symbol	Min	Тур	Max	Unit	Test conditions
Drain to source breakdown voltage	V _{(BR)DSS}	100	—	_	V	$I_D = 10 \text{ mA}, V_{GS} = 0$
Gate to source breakdown voltage	V _{(BR)GSS}	±20	—	_	V	$I_{G} = \pm 100 \ \mu A, \ V_{DS} = 0$
Gate to source leak current	I _{GSS}	_	—	±10	μΑ	$V_{GS} = \pm 16 \text{ V}, \text{ V}_{DS} = 0$
Zero gate voltage drain current	I _{DSS}	_	—	10	μΑ	$V_{DS} = 100 \text{ V}, \text{ V}_{GS} = 0$
Gate to source cutoff voltage	V _{GS(off)}	1.5	—	2.5	V	$I_D = 1 \text{ mA}, V_{DS} = 10 \text{ V}^{Note 4}$
Static drain to source on state	R _{DS(on)}	_	25	35	mΩ	$I_D = 12.5 \text{ A}, V_{GS} = 10 \text{ V}^{Note 4}$
resistance		_	30	45	mΩ	$I_D = 12.5 \text{ A}, V_{GS} = 4.5 \text{ V}^{Note 4}$
Forward transfer admittance	y _{fs}	20	35		S	$I_D = 12.5 \text{ A}, V_{GS} = 10 \text{ V}^{\text{Note 4}}$
Input capacitance	Ciss	_	2800		pF	V _{DS} = 10 V
Output capacitance	Coss	_	240		pF	$V_{GS} = 0$
Reverse transfer capacitance	Crss		140		pF	f = 1 MHz
Total gate charge	Qg		50		nC	V _{DD} = 50 V
Gate to source charge	Qgs		9		nC	V _{GS} = 10 V I _D = 25 A
Gate to drain charge	Qgd		11		nC	
Turn-on delay time	t _{d(on)}	_	23	_	ns	$V_{GS} = 10 \text{ V}, I_D = 12.5 \text{ A}$
Rise time	tr		110		ns	$R_{L} = 2.4 \Omega$ $Rg = 4.7 \Omega$
Turn-off delay time	t _{d(off)}		70		ns	
Fall time	t _f		9.5	_	ns	
Body-drain diode forward voltage	V _{DF}		0.89		V	$I_F = 25 \text{ A}, V_{GS} = 0$
Body-drain diode reverse recovery	t _{rr}	—	45	—	ns	$I_{\rm F} = 25 \text{ A}, V_{\rm GS} = 0$
time						di _F /dt = 100 A/µs

Notes: 4. Pulse test

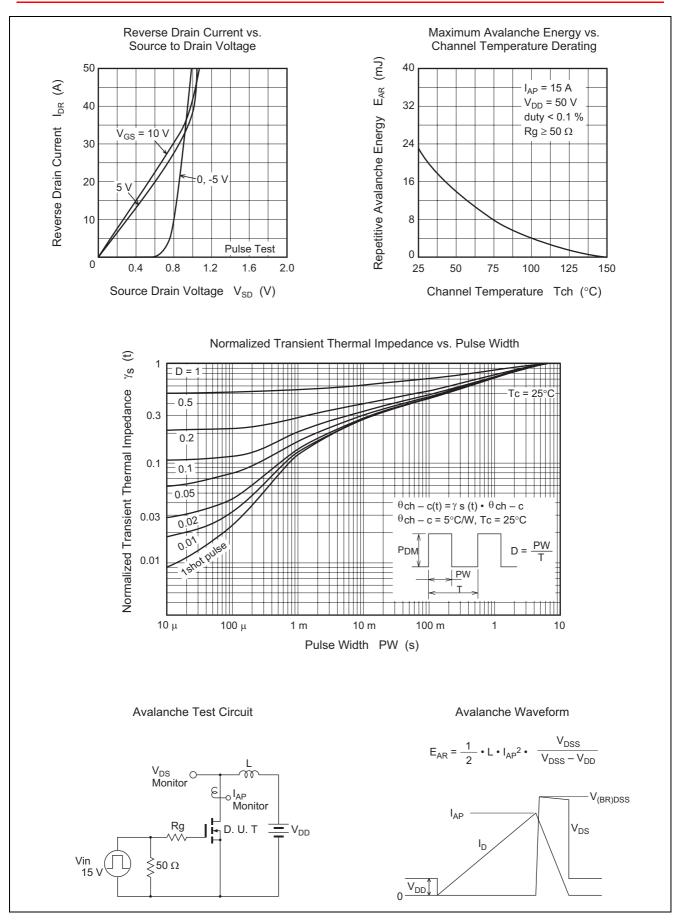
Main Characteristics



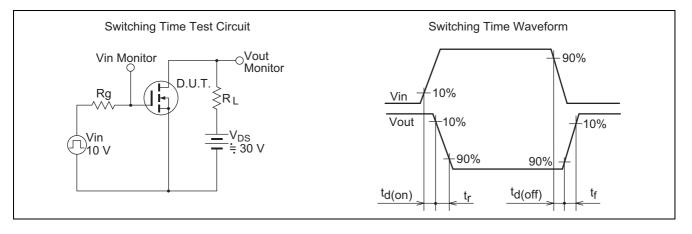
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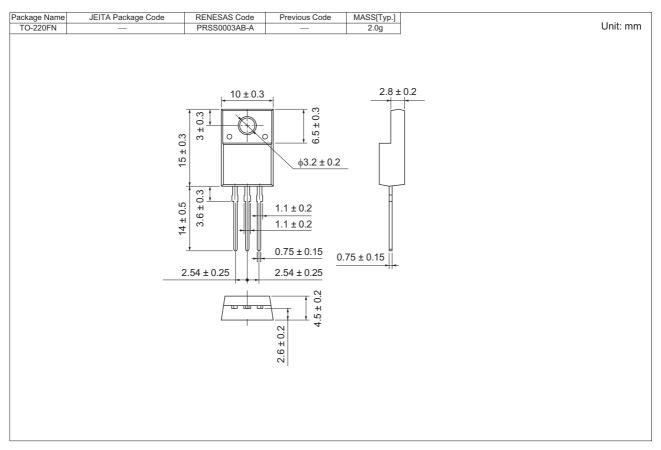
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Package Dimensions



Ordering Information

Part No.	Quantity	Shipping Container
H7N1004FN	50 pcs	Plastic Magazine (Tube)

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